

# isc N-Channel MOSFET Transistor

## IXTP10N60PM

#### • FEATURES

- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 600V(Min)
- · Static drain-source on-resistance
  - : R<sub>DS</sub>(on) ≤  $0.74\Omega@V_{GS}=10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



#### APPLICATION

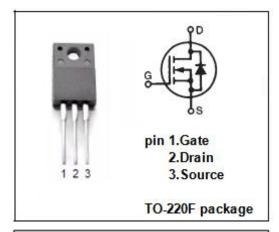
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

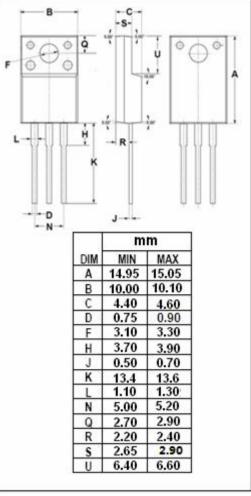
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	600	V	
V <sub>GS</sub>	Gate-Source Voltage	±30		
I <sub>D</sub>	Orain Current-Continuous 5		Α	
I <sub>DM</sub>	Drain Current-Single Pulsed	rain Current-Single Pulsed 30		
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	50	W	
Tj	Operating Junction Temperature	-55~150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}\!\mathbb{C}$	

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{\text{th(j-c)}}$	Junction-to-case thermal resistance	2.5	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID =250 μ A	600		٧
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID =250 μ A	3	5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 5A		0.74	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V		5	- μ Α
		V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V;T <sub>J</sub> =125°C		50	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 10A; V <sub>GS</sub> = 0V		1.5	V



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